

## 3 A Current Mode Constant On-Time Synchronous Buck Regulator



### DESCRIPTION

The SiP12116 is a high frequency current-mode constant on-time (CM-COT) synchronous buck regulator with integrated high side and low side power MOSFETs. Its power stage is capable of supplying up to 3 A continuous current at 600 kHz switching frequency. This regulator produces an adjustable output voltage down to 0.6 V from 4.5 V to 15 V input rail to accommodate a variety of applications, including consumer electronics, computing, telecom, and industrial.

SiP12116's CM-COT architecture delivers ultrafast transient response and low ripple over the full load range with minimum output capacitance and no ESR requirements. The device features a built in soft start of 2.2 ms and integrated compensation.

The device also includes cycle-by-cycle current limit, over temperature protection (OTP) and input under voltage lockout (UVLO).

The SiP12116 is available in lead (Pb)-free 3 mm x 3 mm DFN10-33C lead package with thermal pad.

### FEATURES

- 4.5 V to 15 V input voltage
- Adjustable output voltage down to 0.6 V
- 3 A continuous output current
- Integrated compensation
- 600 kHz switching frequency
- Ultrafast transient response
- < 5  $\mu$ A typical shutdown current
- Cycle by cycle current limit
- Power good function
- Fixed soft start: 2.9 ms, typ.
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### APPLICATIONS

- Graphics cards
- Set -top- box
- LCD TV
- Notebook computers
- HDD / SSD

### TYPICAL APPLICATION CIRCUIT AND PACKAGE OPTIONS

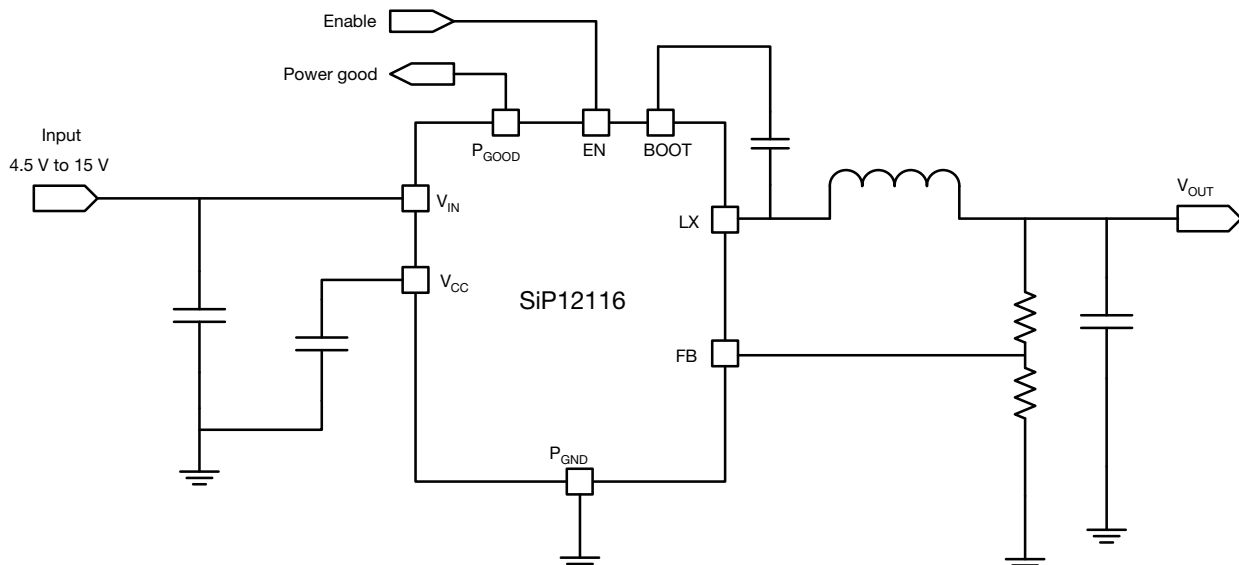
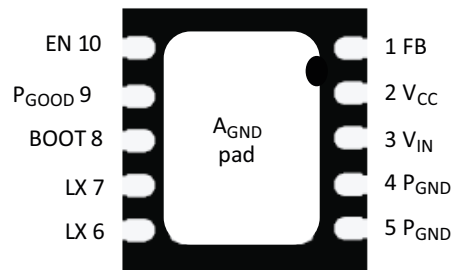
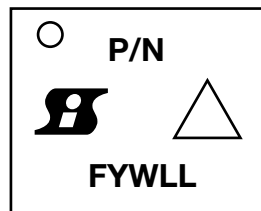


Fig. 1 - Typical Application Circuit for SiP12116

**PIN CONFIGURATION**

**Fig. 2 - SiP12116 Pin Configuration (Bottom View)**

PIN CONFIGURATION		
PIN NUMBER	NAME	FUNCTION
1	FB	Feedback voltage 0.6 V (typ.) input. Use a resistor divider between $V_{OUT}$ and thermal pad to set the output voltage
2	$V_{CC}$	Internal regulator output
3	$V_{IN}$	Input supply voltage for power MOS and regulator. $V_{IN} = 4.5\text{ V to }15\text{ V}$
4, 5	$P_{GND}$	Power ground
6, 7	LX	Switching node, inductor connection point
8	BOOT	Bootstrap pin - connect a capacitor of at least 100 nF from BOOT to LX to develop the floating supply for the high side gate driver
9	$P_{GOOD}$	Power good output. Open drain
10	EN	Enable input. Pull enable above 1.5 V to enable and below 0.4 V to disable the part. Do not float this pin
Pad	$A_{GND}$	Analog ground. The pad also improves thermal performance

ORDERING INFORMATION		
PART NUMBER	PACKAGE	MARKING (LINE 1: P/N)
SiP12116DMP-T1-GE4	DFN10 3 x 3	2116
SiP12116DB	Reference board	

**MARKING**


Format:

- Line 1: Dot
- Line 2: P/N
- Line 3: Siliconix Logo + ESD Symbol
- Line 4: Factory Code + Year Code + Work Week Code + LOT Code



ABSOLUTE MAXIMUM RATINGS			
ELECTRICAL PARAMETER	CONDITIONS	LIMIT	UNIT
V <sub>IN</sub>	Reference to P <sub>GND</sub>	-0.3 to 16	V
V <sub>CC</sub>	Reference to A <sub>GND</sub>	-0.3 to 6	
LX	Reference to P <sub>GND</sub>	-1 to 16	
LX (AC)	100 ns	-2 to 17	
	10 ns	-6 to 17	
BOOT	Reference to P <sub>GND</sub>	-0.3 to V <sub>IN</sub> + V <sub>CC</sub>	
All logic input and output (EN, FB, P <sub>GOOD</sub> )	Reference to A <sub>GND</sub>	-0.3 to V <sub>CC</sub> + 0.3	
TEMPERATURE			
Junction temperature		-40 to +150	°C
Storage temperature		-65 to +150	
POWER DISSIPATION			
Junction-to-ambient thermal impedance (R <sub>thJA</sub> )		36.3	°C/W
ESD PROTECTION			
Electronic discharge protection	HBM	2	kV

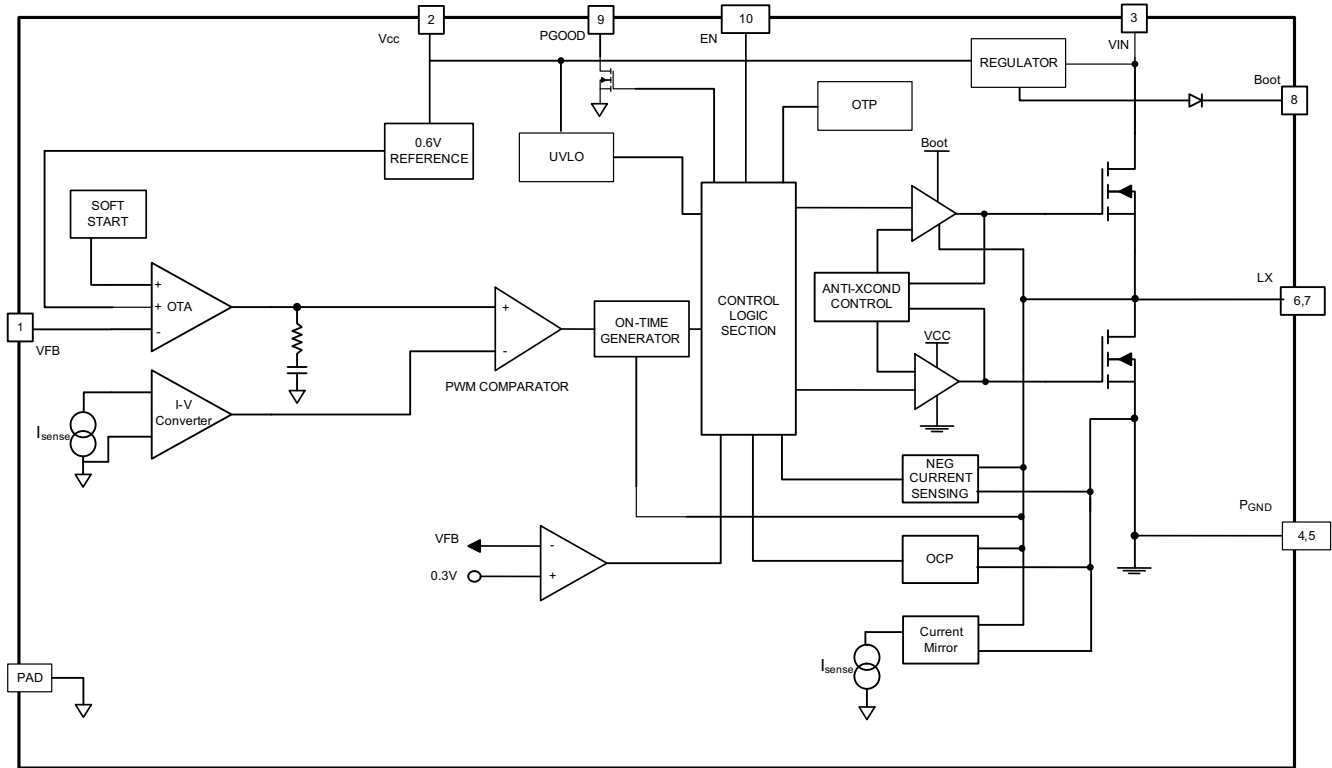
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING RANGE (all voltages referenced to GND = 0 V)				
ELECTRICAL PARAMETER	MINIMUM	TYPICAL	MAXIMUM	UNIT
V <sub>IN</sub>	4.5	-	15	V
V <sub>OUT</sub>	0.6	-	5.5	
TEMPERATURE				
Recommended ambient temperature		-40 to +85		°C
Operating junction temperature		-40 to +125		



<b>ELECTRICAL SPECIFICATIONS</b> (test condition unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITION $V_{IN} = 12\text{ V}$ , $T_A = -40\text{ }^\circ\text{C}$ to $+85\text{ }^\circ\text{C}$	LIMITS			UNIT
			MIN.	TYP.	MAX.	
<b>POWER SUPPLY</b>						
Input voltage	$V_{IN}$		4.5	-	15	V
$V_{CC}$ voltage	$V_{CC}$		-	5	-	
Input current	$I_{VIN\_NOLOAD}$	$T_A = 25\text{ }^\circ\text{C}$ , non-switching, no load	-	1.5	-	mA
Shutdown current	$I_{VIN\_SHDN}$	$EN = 0\text{ V}$	-	5	10	$\mu\text{A}$
$V_{IN}$ UVLO threshold	$V_{IN\_UVLO}$	Rising edge	-	2.8	-	V
$V_{IN}$ UVLO hysteresis	$V_{IN\_UVLO\_HYS}$		-	550	-	mV
<b>CONTROLLER AND TIMING</b>						
Feedback voltage	$V_{FB}$	$T_A = 25\text{ }^\circ\text{C}$	588	600	612	mV
		$T_A = -40\text{ }^\circ\text{C}$ to $+85\text{ }^\circ\text{C}$	585	600	615	
$V_{FB}$ input bias current	$I_{FB}$		-	-	100	nA
On-time (600 kHz)	$t_{ON}$	$V_{IN} = 12\text{ V}$ , ( $V_{OUT} = 1\text{ V}$ )	-	138	-	ns
Soft start timing			0.8	-	5	ms
<b>POWER MOSFETs</b>						
High side on resistance	$R_{ON\_HS}$	$V_{GS} = 5\text{ V}$	-	85	140	m $\Omega$
Low side on resistance	$R_{ON\_LS}$		-	55	105	
<b>FAULT PROTECTIONS</b>						
Over current limit	$I_{OCP}$	Inductor valley current, $T_A = 25\text{ }^\circ\text{C}$	3.6	4.25	5.1	A
Over temperature protection		Rising temperature	-	145	-	$^\circ\text{C}$
		Hysteresis	-	35	-	
<b>POWER GOOD</b>						
Power good output threshold	$V_{FB\_RISING\_VTH\_OV}$	Rising (% $V_{OUT}$ )	-	95	-	%
	$V_{FB\_FALLING\_VTH\_UV}$	Falling (% $V_{OUT}$ )	-	-10	-	
Power good pull low resistance	$R_{ON\_PGOOD}$		-	28	50	$\Omega$
Power good delay Time	$t_{DLY\_PGOOD}$		-	8	-	$\mu\text{s}$
<b>ENABLE THRESHOLD</b>						
Logic high level	$V_{EN\_H}$		1.5	-	-	V
Logic low level	$V_{EN\_L}$		-	-	0.4	

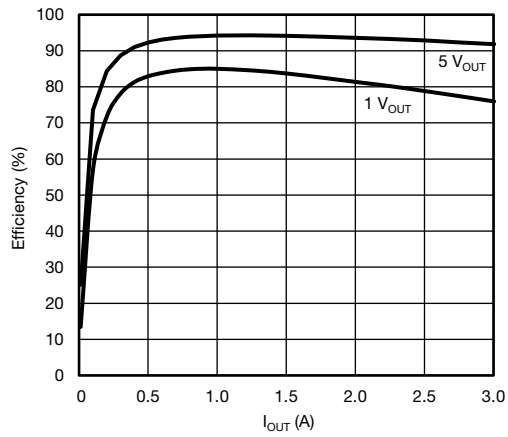
**FUNCTIONAL BLOCK DIAGRAM**



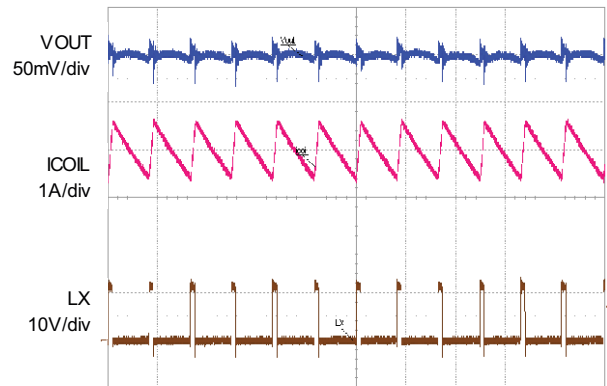
**Fig. 3 - SiP12116 Functional Block Diagram**

**ELECTRICAL CHARACTERISTICS**

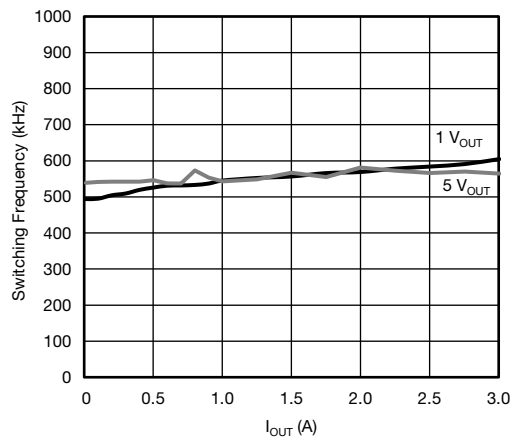
( $V_{IN} = 12\text{ V}$ ,  $V_{OUT} = 1\text{ V}$ ,  $L = 1.5\ \mu\text{H}$ ,  $C = 3 \times 22\ \mu\text{F}$  (ceramic), unless noted otherwise)



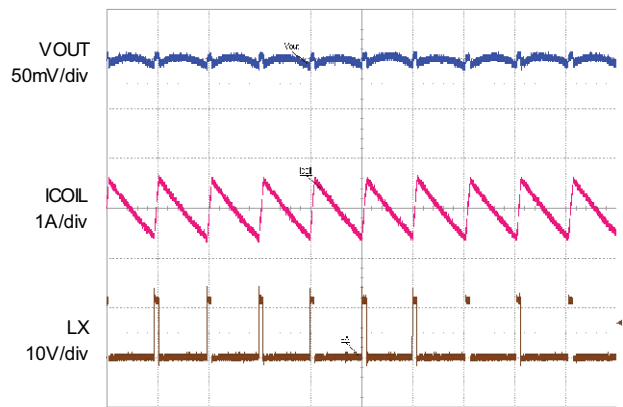
**Fig. 4 - Efficiency vs.  $I_{OUT}$**



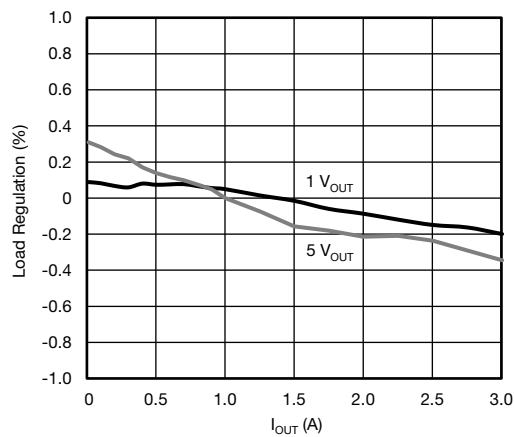
**Fig. 7 - Steady-State,  $I_{OUT} = 3\text{ A}$ , Time =  $2\ \mu\text{s}/\text{div}$**



**Fig. 5 - Frequency Variation vs.  $I_{OUT}$**



**Fig. 8 - Steady-State,  $I_{OUT} = 0\text{ A}$ , Time =  $2\ \mu\text{s}/\text{div}$**



**Fig. 6 - Load Regulation vs.  $I_{OUT}$**

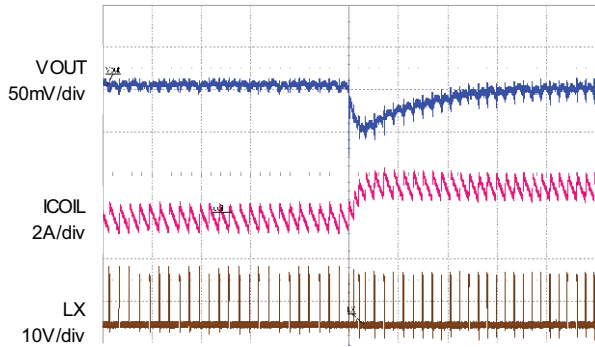


Fig. 9 - Load Step Undershoot Response,  $I_{OUT} = 0 \text{ A to } 1.5 \text{ A}$ , Time = 10  $\mu\text{s/div}$

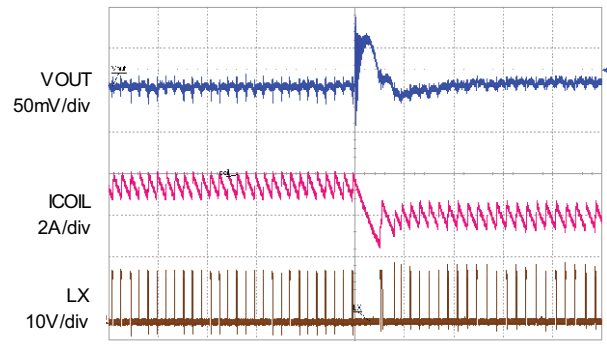


Fig. 12 - Load Step Overshoot Response,  $I_{OUT} = 1.5 \text{ A to } 0 \text{ A}$ , Time = 10  $\mu\text{s/div}$

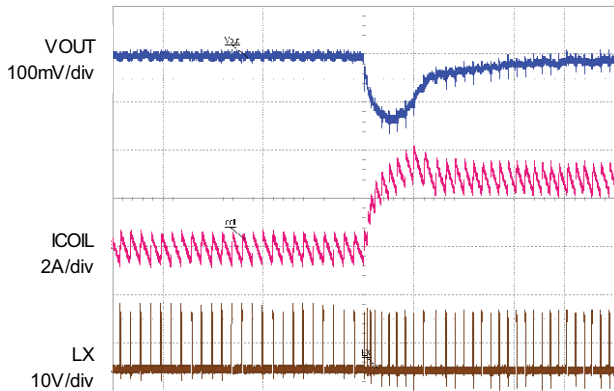


Fig. 10 - Load Step Undershoot Response,  $I_{OUT} = 0 \text{ A to } 3 \text{ A}$ , Time = 10  $\mu\text{s/div}$

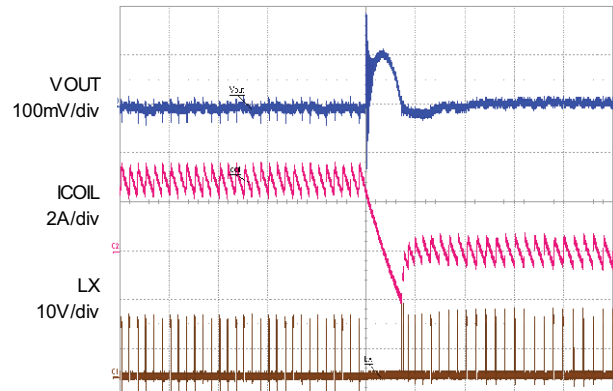


Fig. 13 - Load Step Overshoot Response,  $I_{OUT} = 3 \text{ A to } 0 \text{ A}$ , Time = 10  $\mu\text{s/div}$

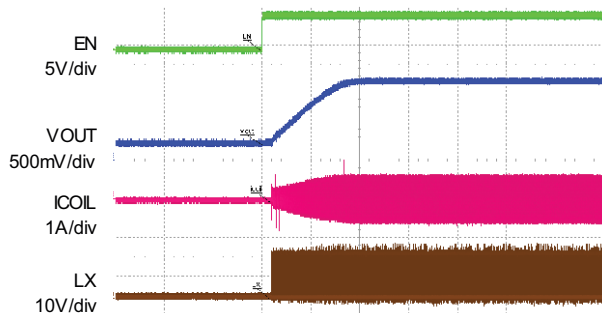


Fig. 11 - Start-Up,  $I_{OUT} = 0 \text{ A}$ , Time = 1  $\mu\text{s/div}$

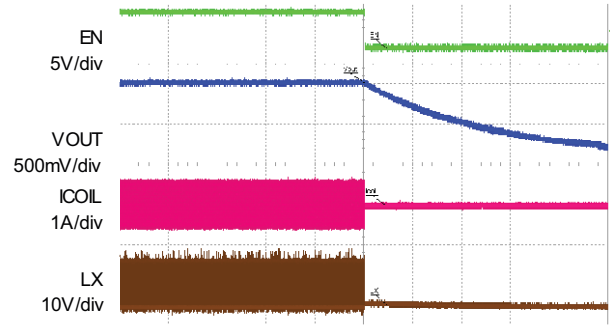


Fig. 14 - Shut-Down,  $I_{OUT} = 0 \text{ A}$ , Time = 200  $\text{ms/div}$

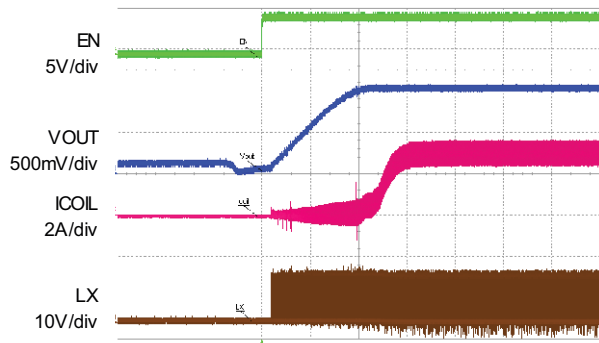


Fig. 15 - Load Step Undershoot Response  $I_{OUT} = 0\text{ A}$  to  $3\text{ A}$ , Time =  $1\text{ ms/div}$

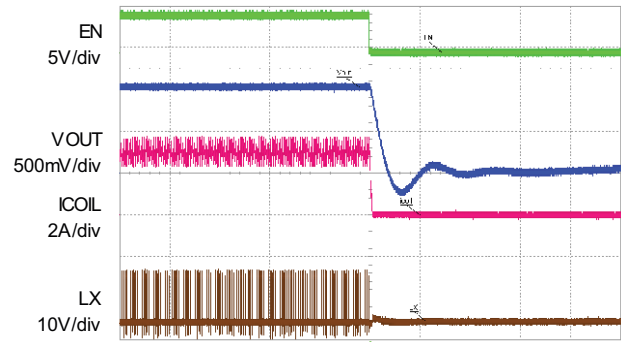


Fig. 17 - Shut-Down,  $I_{OUT} = 3\text{ A}$ , Time =  $50\text{ }\mu\text{s/div}$

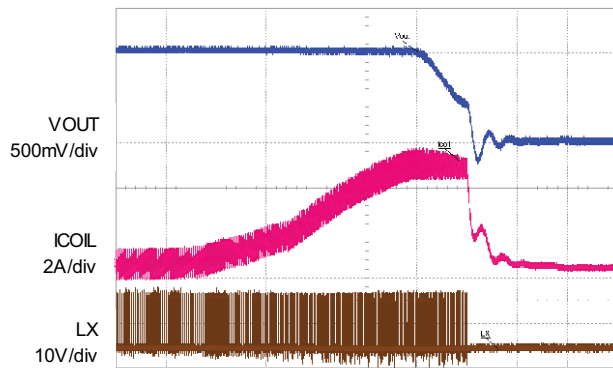


Fig. 16 - Over Current Protection,  $I_{VALLEY} = 4\text{ A}$ , Time =  $100\text{ }\mu\text{s/div}$

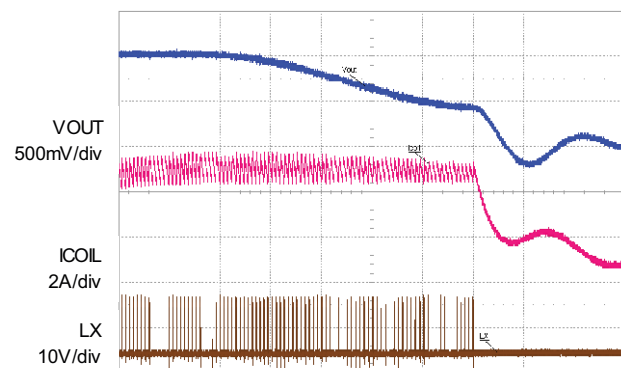


Fig. 18 - Over Current Protection,  $I_{VALLEY} = 4\text{ A}$ , Time =  $20\text{ }\mu\text{s/div}$



**OPERATIONAL DESCRIPTION**

**Device Overview**

SiP12116 is a high efficiency monolithic synchronous buck regulator capable of delivering up to 3 A continuous current. The device has fixed switching frequency of 600 kHz. The control scheme is based on current - mode constant-on-time architecture, which delivers fast transient response and minimizes external components. Thanks to the internal current ramp information, no high ESR output bulk or virtual ESR network is required for the loop stability. SiP12116 has a full set of protection features:

- Cycle by cycle over current protection
- Over temperature protection with hysteresis

The device also features a dedicated enable pin for easy power sequencing and an open drain Power Good output.

The device is available in 3x3 DFN10 package with an exposed power pad to deliver high power density with ease of use.

**Power Stage**

SiP12116 integrates a high performance power stage with an 85 mΩ n-channel high side MOSFET and a 55 mΩ n-channel low side MOSFET. The MOSFETs are optimized to achieve up to 95 % efficiency at 600 kHz switching frequency.

The power input voltage ( $V_{IN}$ ) can go up to 15 V and down as low as 4.5 V for power conversion.

**PWM Control Mechanism**

SiP12116 employs a state-of-the-art current - mode COT (CM-COT) control mechanism. During steady-state operation, output voltage is compared with internal reference (0.6 V typ.) and the amplified error signal ( $V_{comp}$ ) is generated. In the meantime, inductor valley current is sensed, and its slope ( $I_{sense}$ ) is converted into a voltage signal ( $V_{current}$ ) to be compared with  $V_{comp}$ . Once  $V_{current}$  is lower than  $V_{comp}$ , a single shot ON-time is generated for a fixed time set by an internal  $R_{ON}$ .

Figure 19 illustrates the basic block diagram for CM-COT architecture and Figure 20 demonstrates the basic operational principle:

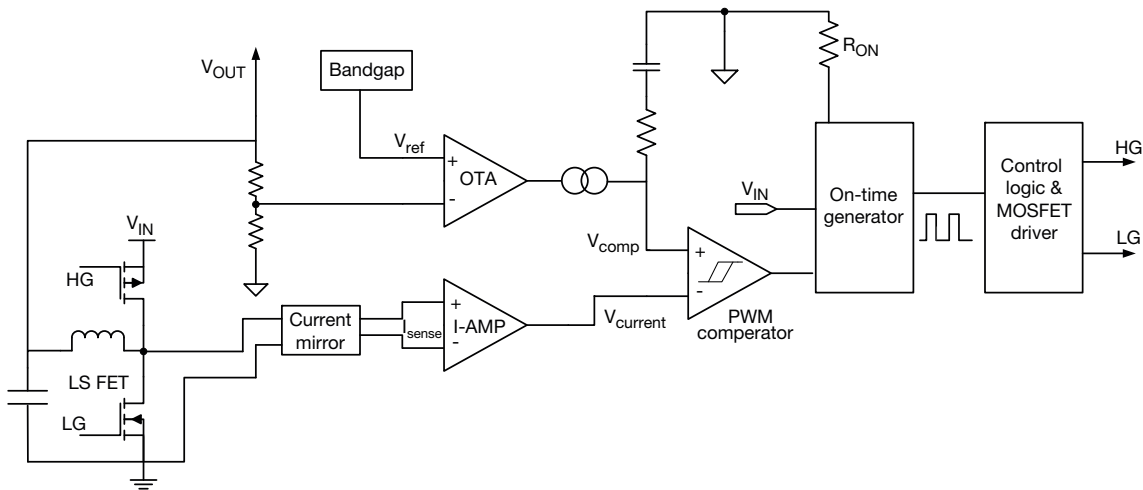


Fig. 19 - CM-COT Block Diagram

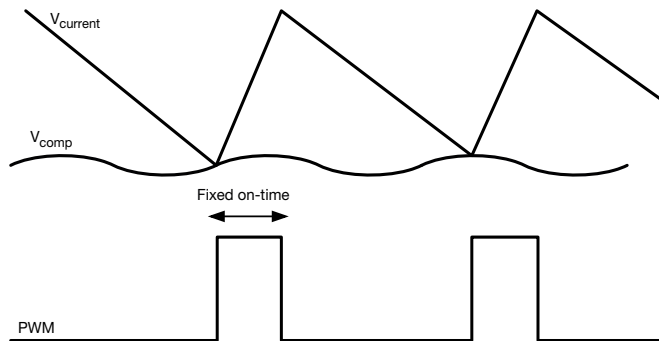


Fig. 20 - CM-COT Operational Principle

## OUTPUT MONITORING AND PROTECTION FEATURES

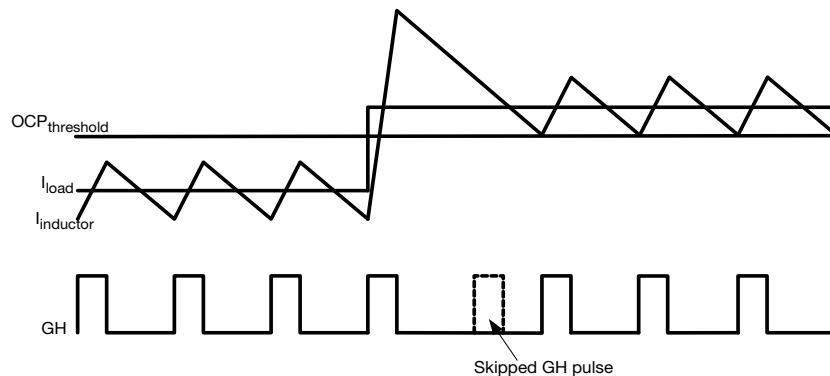
### Output Over Current Protection (OCP)

SiP12116 has cycle by cycle over current limit control. The inductor valley current is monitored during LS FET turn-on period through  $R_{DS(on)}$  sensing. After a pre-defined blanking time, the valley current is compared with internal threshold (4.25 A typ.) to determine the threshold for OCP. If the monitored current is higher than the internal threshold, HS turn-on pulse is skipped and LS FET is kept on until the valley current returns below OCP limit.

OCP is enabled immediately after  $V_{IN}$  passes UVLO level and enable is high.

In the figure below we see the ripple current riding on the DC load current. The valley current is calculated by taking one half the ripple current minus the DC load current.

For example if  $I_{OUT} = 3$  A and ripple current = 1.2 A,  $I_{VALLEY} = 3$  A - 0.6 A = 2.4 A. The typical DC full load current would be 4.85 A which is calculated by 4.25 A (OCP typ.) + 0.6 A. Here we see changing the ripple current (inductor value) can change the maximum DC load current value.



**Fig. 21 - Over Current Protection Illustration**

### Negative Current Protection

Similar to the output over current protection, the negative current protection is realized by monitoring the current across the LS FET.

When the valley point of the inductor current reaches -2.5 A for first cycles, both HS and LS FETs are off.

### Over Temperature Protection (OTP)

SiP12116 has internal thermal monitor block that turns off both HS and LS FETs when junction temperature is above 145 °C (typ.). A hysteresis of 35 °C is implemented, so when junction temperature drops below 110 °C, the device restarts by initiating soft-start sequence again.

### Soft Start

SiP12116 has a built in soft-start function of ~ 2.2 ms. Once  $V_{IN}$  is above UVLO level (3.33 V typ.),  $V_{OUT}$  will ramp up slowly, rising monotonically to the programmed output voltage.

### Pre-bias Startup

In case of pre-bias startup, the output is monitored through the FB pin. If the sensed voltage on FB is higher than the internal reference ramp value, control logic prevents HS and LS FET from switching to avoid a negative output voltage spike due to LS FET turn on.

### Design Procedure

The design process of the SiP12116 is quite straight forward. Only few passive components such as output capacitors and inductor need to be selected.

The following paragraph describes the selection procedure for these peripheral components for a given operating conditions.

In the next example the following definitions apply:

$V_{IN}$  max.: the highest specified input voltage

$V_{IN}$  min.: the minimum effective input voltage subject to voltage drops due to connectors, fuses, switches, and PCB traces.

There are two values of load current to evaluate - continuous load current and peak load current.

Continuous load current relates to thermal stress considerations which drive the selection of the inductor and input capacitors.

Peak load current determines instantaneous component stresses and filtering requirements such as inductor saturation, output capacitors, and design of the current limit circuit.

The following specifications are used in this design:

- $V_{IN} = 12$  V  $\pm$  10 %
- $V_{OUT} = 1.2$  V  $\pm$  1 %

### Inductor Selection

In order to determine the inductance, the ripple current must first be defined. Cost, PCB size, output ripple, and efficiency are all used in the selection process. Low inductor values result in smaller size and allow faster transient performance but create higher ripple current which can reduce efficiency. Higher inductor values will reduce the ripple current, and transient response. Efficiency especially at higher load currents will also be compromised due to the higher DCR (within a given case size).

The ripple current also sets the boundary for power-save operation. The switching regulator will typically enter power-save mode when the load current decreases to 1/2 of the ripple current. For example, if ripple current is 1 A then power-save operation will typically start at loads approaching 0.5 A. Alternatively, if ripple current is set at 40 % of maximum load current, then power-save will start for loads less than ~ 20 % of maximum current.

Setting the ripple current 20 % to 50 % of the maximum load current provides an optimal trade-off of the areas mentioned above.

This table provides a simple easy guide for setting up the board. If excessive jitter is noticed then reducing the inductor to the next standard value may be needed.

<b>SiP12116 CONFIGURATION LOOK UP TABLE</b>				
<b>V<sub>IN</sub></b> <b>(V)</b>	<b>V<sub>OUT</sub></b> <b>(V)</b>	<b>INDUCTOR</b> <b>(μH)</b>	<b>R<sub>FB TOP</sub></b> <b>(Ω)</b>	<b>R<sub>FB BOTTOM</sub></b> <b>(Ω)</b>
12	1	1.5	4.53K	6.81K
12	3.3	3.3	4.53K	1K
12	5	3.3	4.53K	619R
5	1	1.5	4.53K	6.81K
5	3.3	1.5	4.53K	1K

The equation for determining inductance is shown next.

#### Example

In this example, the inductor ripple current is set equal to 30 % of the maximum load current. Thus ripple current will be 30 % x 3 A or 0.9 A. To find the minimum inductance needed, use the V<sub>IN</sub> and t<sub>ON</sub> values that correspond to V<sub>IN max.</sub>

$$L = (V_{IN} - V_{OUT}) \times \frac{t_{ON}}{\Delta i}$$

Plugging numbers into the above equation we get

$$L = (13.2 \text{ V} - 1.2 \text{ V}) \times \frac{151 \times 10^{-9} \text{ s}}{0.9 \text{ A}} = 2 \mu\text{H}$$

A smaller value of 1.5 μH is selected which is a standard value. This will increase the maximum ripple current by 25 %.

Note that the inductor must be rated for the maximum DC load current plus 1/2 of the ripple current. The actual ripple current using the chosen 1 μH inductor comes out to be.

$$\Delta i = (13.2 \text{ V} - 1.2 \text{ V}) \times \frac{151 \text{ ns}}{1.5 \mu\text{H}} = 1.2 \text{ A}$$

### Output Capacitance Calculation

The output capacitance is usually chosen to meet transient requirements. A worst-case load release, from maximum load to no load at the exact moment when inductor current is at the peak, determines the required capacitance. If the load release is instantaneous (load changes from maximum to zero in < 1/f<sub>sw</sub> μs), the output capacitor must absorb all the inductor's stored energy. This will approximately cause a peak voltage on the capacitor according to the following equation.

$$C_{OUT \text{ min.}} = \frac{L \times (I_{OUT} + \frac{1}{2} \times I_{RIPPLE \text{ max.}})^2}{(V_{PEAK})^2 - (V_{OUT})^2}$$

Assuming a peak voltage V<sub>PEAK</sub> of 1.3 V (100 mV rise upon load release), and a 3 A load release, the required capacitance is shown by the next equation.

$$C_{OUT \text{ min.}} = \frac{1.5 \mu\text{H} \times (3 \text{ A} + 0.5 \times (1.2 \text{ A}))^2}{(1.3 \text{ V})^2 - (1.2 \text{ V})^2} = 77.8 \mu\text{F}$$

If the load release is relatively slow, the output capacitance can be reduced.

Using MLCC ceramic capacitors we will use 3 x 22 μF or 66 μF as the total output capacitance.

### Switching Frequency Variations

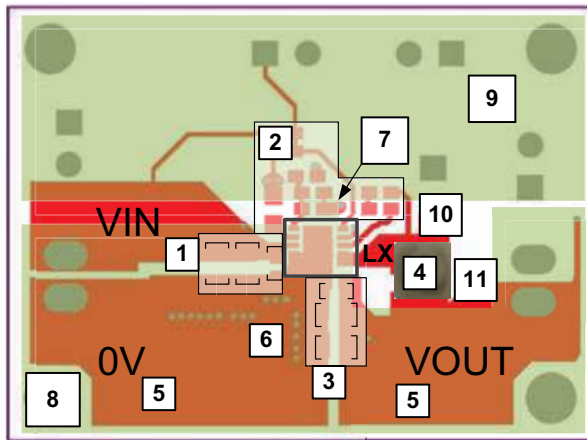
The switching frequency variation in COT can be mainly attributed to the increase in conduction losses as the load increases. Since the on time is constant the controller must account for losses and maintain output regulation by reducing the off time. Hence the f<sub>sw</sub> tends to increase with load.

## LAYOUT CONSIDERATIONS

The SiP12116 offers the designer a small part count, 3 A buck regulator solution. If the below layout recommendations are followed, the same layout can be used to cover a wide range of output currents and voltages without any changes to the board design and only minor changes to the component values in the schematic.

The reference design has a majority of the components placed on the top layer. This allows for easy assembly and straightforward layout.

Figure 22 outlines the pointers for the layout considerations and the explanations follow.



**Fig. 22 - Reference Design Pointers**

1. Place input ceramic capacitors close to the voltage input pins with a small 10 nF / 100 nF placed as close as the design rules will allow. This will help reduce the size of the input high frequency current loop and consequently reduce the high frequency ripple noise seen at the input and the LX node.
2. Place the setup and control passive devices logically around the IC with the intention of placing a quiet ground plane beneath them on a secondary layer.
3. It is advisable to use ceramic capacitors at the output to reduce impedance. Place these as close to the IC  $P_{GND}$  and output voltage node as design will allow. Place a small 10 nF / 100 nF ceramic capacitor closest to the IC and inductor loop.
4. The loop between LX,  $V_{OUT}$  and the IC  $P_{GND}$  should be as compact as possible. This will lower series resistance and also make the current loop smaller enabling the high frequency response of the output capacitors to take effect.
5. The output impedance should be small when high current is required; use high current traces, multiple layers can be used with many vias if the design allows.
6. Use many vias when multiple layers are involved. This will have the effect of lowering the resistance between layers and reducing the via inductance of the PCB nets.
7. The quiet  $A_{GND}$  should be connected to the  $P_{GND}$  plane near the input GND at one connection only of at least 1 mm width.
8.  $P_{GND}$  can be used on internal layers if the resistance of the PCB is to be small; this will also help remove heat. Use extra vias if needed but be mindful to allow a path between the vias.
9. A quiet plane should be employed for the  $A_{GND}$ , this is placed under the small signal passives. This can be placed on multiple layers if needed for heat removal.
10. The LX copper can also be used on a single or multiple layers, use a number of vias to stitch the layers.
11. The copper area beneath the inductor has been removed (on all layers) in this design to reduce the inductive coupling that occurs between the inductor and the GND trace. No other voltage planes should be placed under this area.

PCB LAYOUT

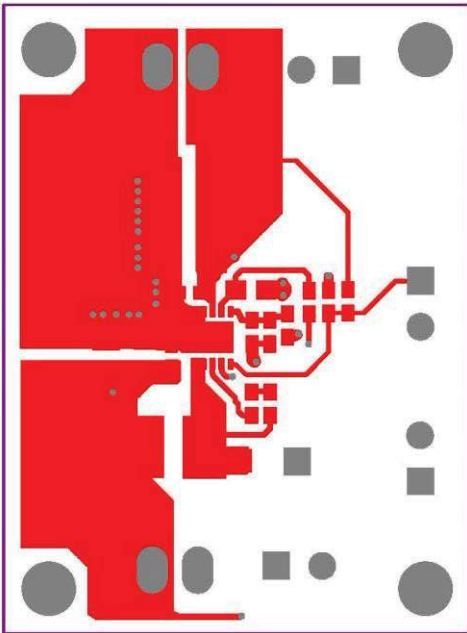


Fig. 23 - Top Layer

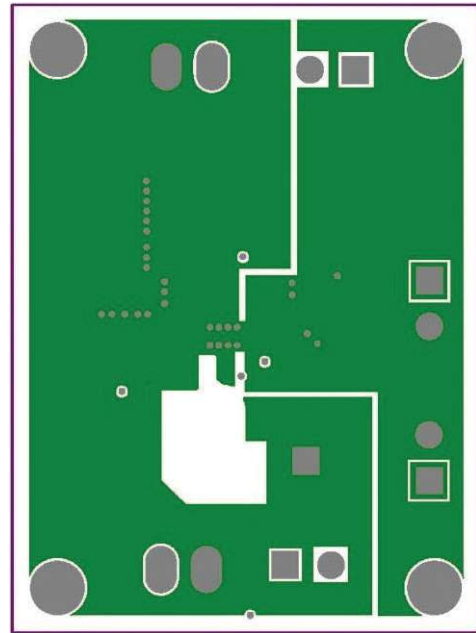


Fig. 25 - Inner Layer 1

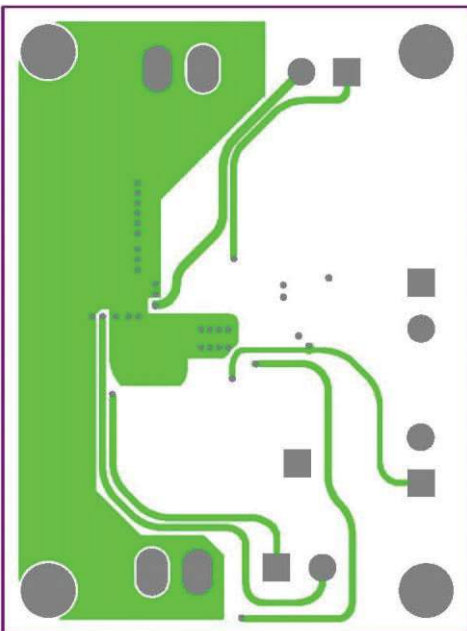


Fig. 24 - Inner Layer 2

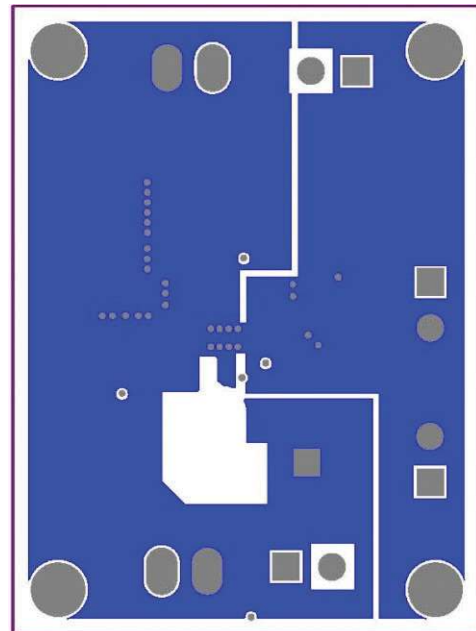
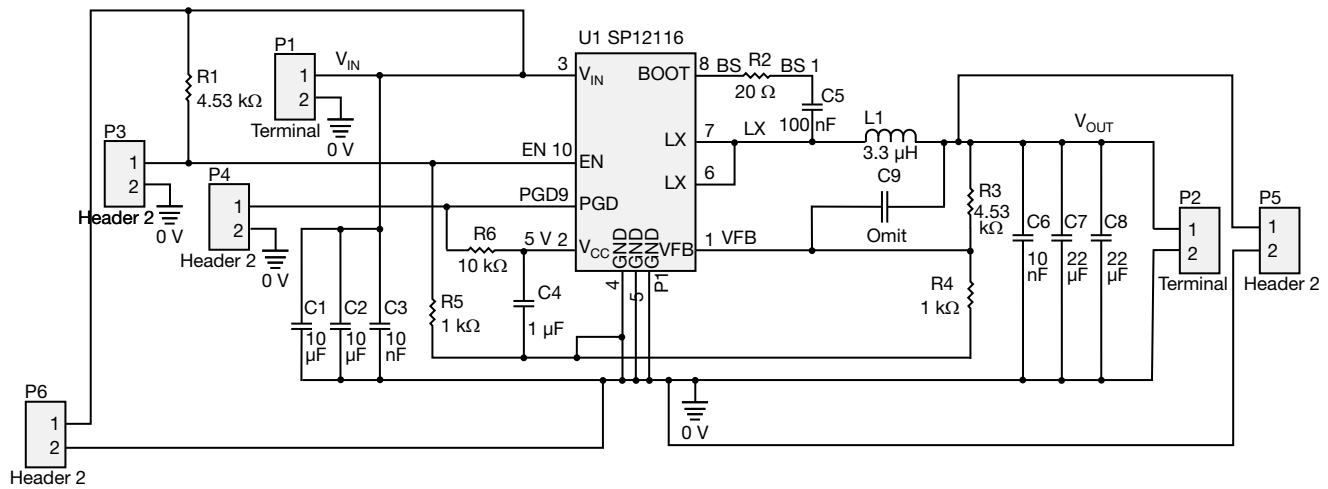


Fig. 26 - Bottom Layer

**SCHEMATIC**


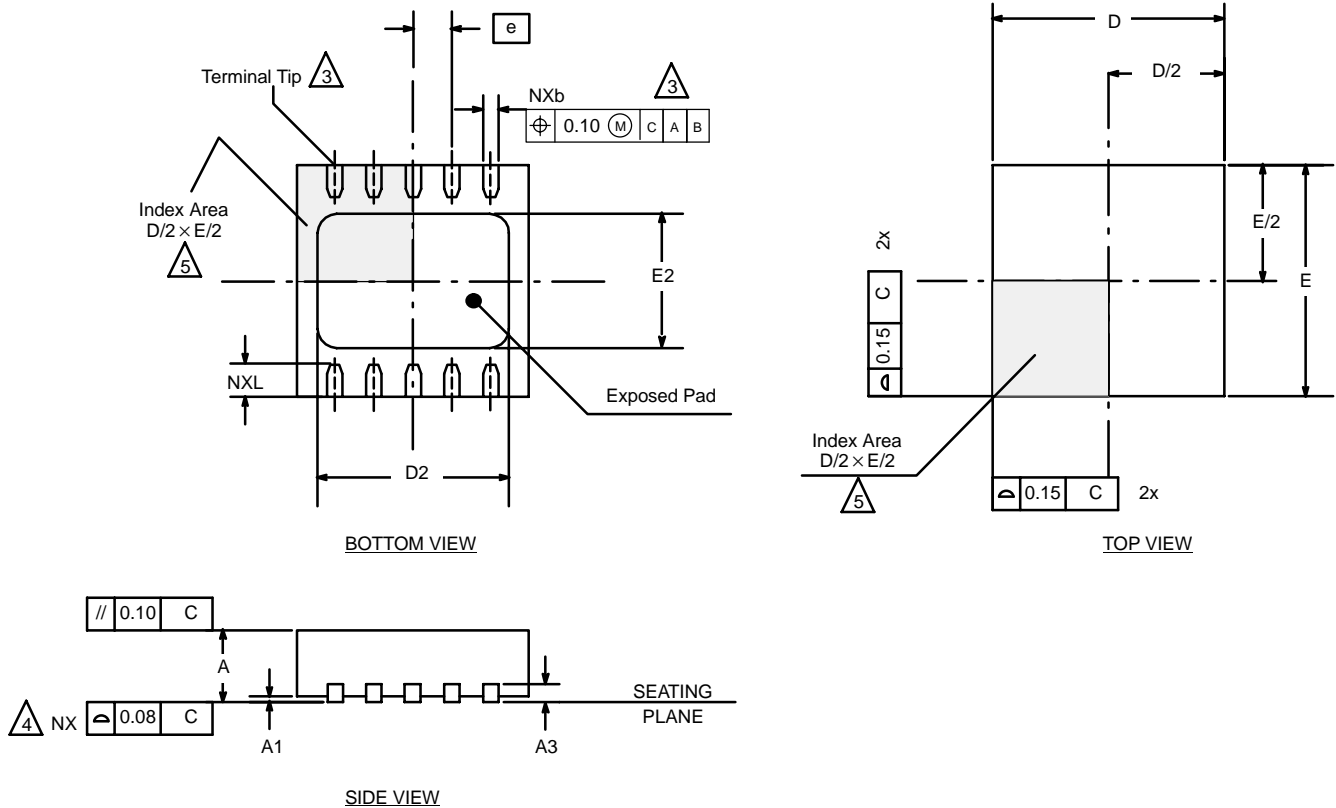
BILL OF MATERIAL $V_{IN} = 12\text{ V}$ , $V_{OUT} = 3.3\text{ V}$ , $f_{SW} = 600\text{ kHz}$							
ITEM	QTY	REFERENCE	PCB FOOTPRINT	VALUE	VOLTAGE	PART NUMBER	MANUFACTURER
1	2	C1, C2	1210	10 $\mu\text{F}$	35 V	C1210C106M6PACTU	Kemet
2	2	C3, C6	0402	10 nF	50 V	GRM155R71H103KA88D	Murata
3	1	C4	0603	1 $\mu\text{F}$	10 V	C0402C105M8PACTU	Kemet
4	1	C5	0402	100 nF	35 V	CGA2B3X7R1V104K050BB	Vishay
5	2	C7, C8	0805	22 $\mu\text{F}$	10 V	CL21A226MPQNNNE	Samsung
6	1	R2	0402	20 $\Omega\text{R}$	-	CRCW040220R0FKED	Vishay
7	1	R3	0402	4.53 k $\Omega$	-	CRCW04024K53FKED	Vishay
8	1	R4	0402	1 k $\Omega$	-	CRCW0402249KFKED	Vishay
9	1	L1	IHLP2525	3.3 $\mu\text{H}$	-	IHLP2020BZER3R3M01	Vishay
10	1	U1	DFN10-3x3	-	-	SiP12116	Vishay
11	1	R1	0402	4.53 k $\Omega$	-	CRCW04024K53FKED	Vishay
12	1	R5	0402	1 k $\Omega$	-	CRCW0402249KFKED	Vishay
13	1	R6	0402	10 k $\Omega$	-	CRCW040210K0FKED	Vishay
14	4	P3, P4, P5, P6	HDR1x2	-	-	90120-0126	Vishay
15	2	P1, P2	TERM2	-	-	282834-2	TE Connectivity



<b>PRODUCT SUMMARY</b>	
Part number	SiP12116
Description	3 A, 4.5 V to 15 V input, current mode constant on-time, synchronous buck regulator
Input voltage min. (V)	4.5
Input voltage max. (V)	15
Output voltage min. (V)	0.6
Output voltage max. (V)	5.5
Continuous current (A)	3
Switch frequency min. (kHz)	600
Switch frequency max. (kHz)	600
Pre-bias operation (yes / no)	Yes
Internal bias reg. (yes / no)	No
Compensation	Integrated
Enable (yes / no)	Yes
P <sub>GOOD</sub> (yes / no)	Yes
Overcurrent protection	Fixed
Protection	OCP, OTP, UVLO
Light load mode	n/a
Peak efficiency (%)	95
Package type	DFN10-33C
Package size (W, L, H) (mm)	3 x 3 x 0.9
Status code	2
Product type	microBUCK (step down regulator)
Applications	Computing, consumer, networking

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?62969](http://www.vishay.com/ppg?62969).

### DFN-10 LEAD (3 X 3)



**NOTES:**

- All dimensions are in millimeters and inches.
- N is the total number of terminals.
- $\triangle 3$  Dimension b applies to metallized terminal and is measured between 0.15 and 0.30 mm from terminal tip.
- $\triangle 4$  Coplanarity applies to the exposed heat sink slug as well as the terminal.
- $\triangle 5$  The pin #1 identifier may be either a mold or marked feature, it must be located within the zone indicated.

Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
<b>A</b>	0.80	0.90	1.00	0.031	0.035	0.039
<b>A1</b>	0.00	0.02	0.05	0.000	0.001	0.002
<b>A3</b>	0.20 BSC			0.008 BSC		
<b>b</b>	0.18	0.23	0.30	0.007	0.009	0.012
<b>D</b>	3.00 BSC			0.118 BSC		
<b>D2</b>	2.20	2.38	2.48	0.087	0.094	0.098
<b>E</b>	3.00 BSC			0.118 BSC		
<b>E2</b>	1.49	1.64	1.74	0.059	0.065	0.069
<b>e</b>	0.50 BSC			0.020 BSC		
<b>L</b>	0.30	0.40	0.50	0.012	0.016	0.020
*Use millimeters as the primary measurement.						
ECN: S-42134—Rev. A, 29-Nov-04						
DWG: 5943						





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